

MOS FIELD EFFECT TRANSISTOR **2SK3204**

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3204 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Low on-state resistance : $R_{DS(on)1} = 34 \text{ m}\Omega \text{ MAX. (Vgs} = 10 \text{ V, Id} = 8 \text{ A})$
- $R_{DS(on)2} = 50 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4 \text{ V}, \text{ ID} = 8 \text{ A})$
- Low Ciss : Ciss = 940 pF TYP.
- Built-in gate protection diode.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	Vdss	60	V
Gate to Source Voltage ($V_{DS} = 0 V$)	VGSS(AC)	±20	V
Gate to Source Voltage ($V_{DS} = 0 V$)	VGSS(DC)	+20, -10	V
Drain Current (DC) (Tc = 25 °C)	D(DC)	±15	А
Drain Current (pulse) Note1	D(pulse)	±45	А
Total Power Dissipation ($T_A = 25^{\circ}C$)	Рт	1.8	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note2	las	15	А
Single Avalanche Energy ^{Note2}	Eas	22.5	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting $T_{ch} = 25^{\circ}C$, $V_{DD} = 30 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$

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ORDERING INFORMATION

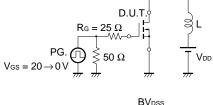
PART NUMBER	PACKAGE	
2SK3204	MP-10	

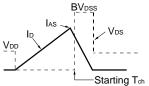
ELECTRICAL CHARACTERISTICS (TA = 25°C)

PARAMATERS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Idss	Vds = 60 V, Vgs = 0 V			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	VGS(off)	Vbs = 10 V, lb = 1 mA	1.0	1.5	2.0	V
Forward Transfer Admittance	yfs	Vds = 10 V, Id = 8 A	8.0	14		S
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 8 A		25	34	mΩ
	RDS(on)2	Vgs = 4 V, Id = 8 A		35	50	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		940		pF
Output Capacitance	Coss	V _{GS} = 0 V		290		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		120		pF
Turn-on Delay Time	td(on)	Vdd = 30 V, Id = 8 A		17		ns
Rise Time	tr	Vgs = 10 V		150		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		58		ns
Fall Time	tr			52		ns
Total Gate Charge	QG	V _{DD} = 48 V		25		nC
Gate to Source Charge	QGS	VGS(on) = 10 V		2.9		nC
Gate to Drain Charge	Qgd	ID = 15 A		7.5		nC
Body Diode Forward Voltage	VF(S-D)	IF = 15 A, VGS = 0 V		0.92		V
Reverse Recovery Time	trr	IF = 15 A, VGS = 0 V		45		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		81		nC

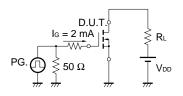
TEST CIRCUIT 1 AVALANCHE CAPABILITY

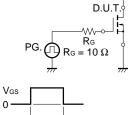
★ TEST CIRCUIT 2 SWITCHING TIME





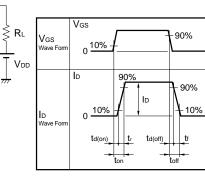
TEST CIRCUIT 3 GATE CHARGE



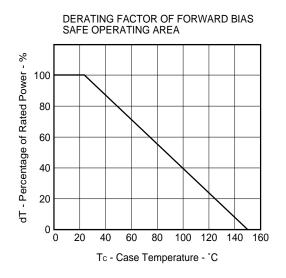


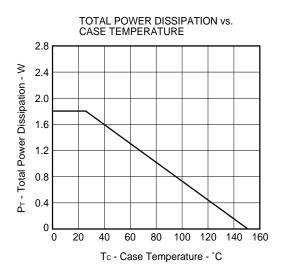
 $\begin{array}{l} \tau = 1 \; \mu s \\ \text{Duty Cycle} \leq 1\% \end{array}$

τ

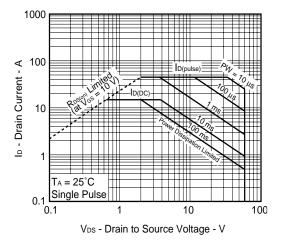


***** TYPICAL CHARACTERISTICS (T_A = 25°C)

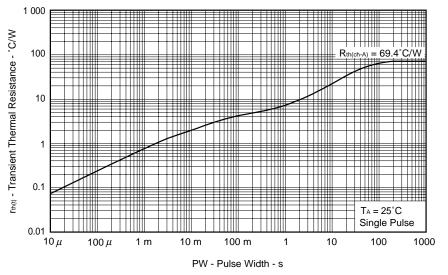




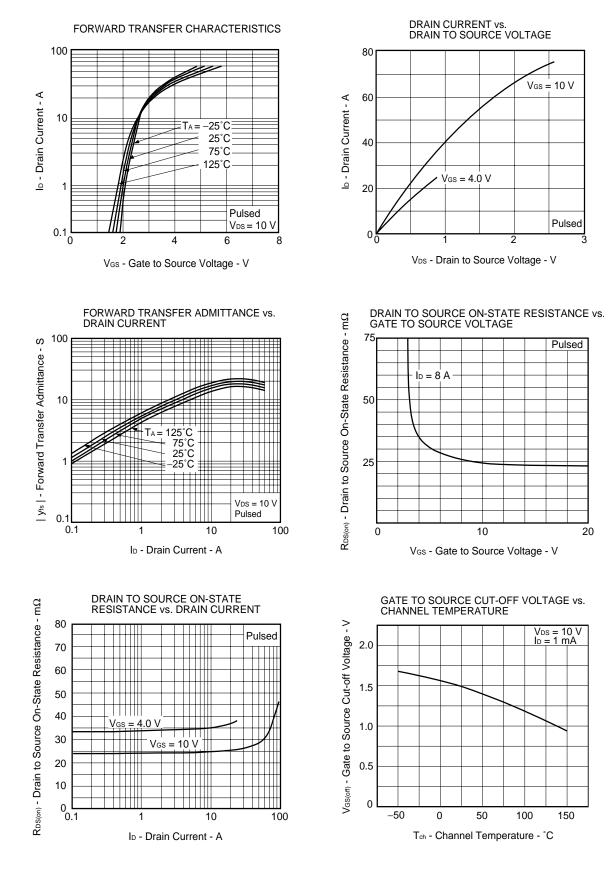
FORWARD BIAS SAFE OPERATING AREA

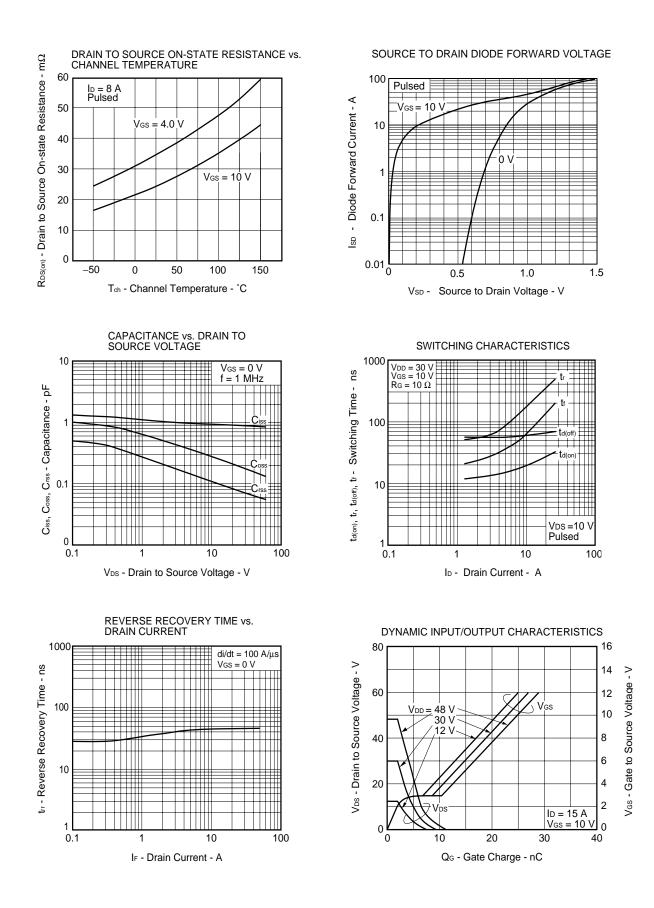


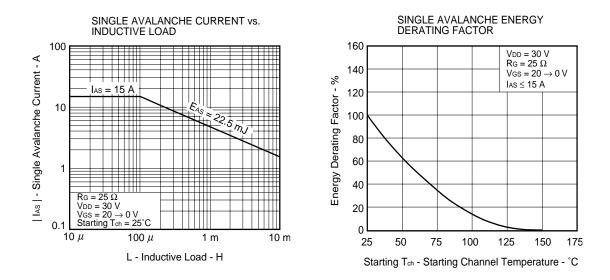
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



Data Sheet D13796EJ2V0DS

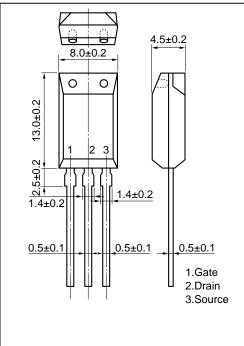




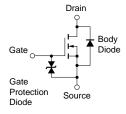


MP-10

PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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